

PART NUMBERING SYSTEM

ISOMOS™ PHOTO MOS RELAY

STANDARD & SOP

Example part number:

WPPM - 35 2 8 S - TRU
(1) (2) (3) (4) (5) (6)

(1) Photo MOS

(2) Load Voltage

06: 60V
10: 100V
20: 200V
35: 350V
40: 400V

(3) Contact Characteristics

2: 1 Form A
4: 1 Form B
6: 1 Form A + 1 Form B
8: Dual Form A
10: Dual Form B

(4) Pin Configuration

4: 4 pin
6: 6 pin
8: 8 pin
16: 16 pin

(5) Package Types

D: DIP
A: SMD
S: SOP

(6) Taping

TLD: Tape Direction Left
TRU: Tape Direction Right

CUSTOM VERSIONS

Example part number:

WPPML - 35 2 4 S - TRU
(1) (2) (3) (4) (5) (6)

(1) Photo MOS Custom

(2) Load Voltage

35: 350V
06: 60V (only available in SOP package)

(3) Contact Characteristics

2: 1 Form A

(4) Pin Configuration

4: 4 pin

(5) Package Types

D: DIP
A: SMD
S: SOP

(6) Taping

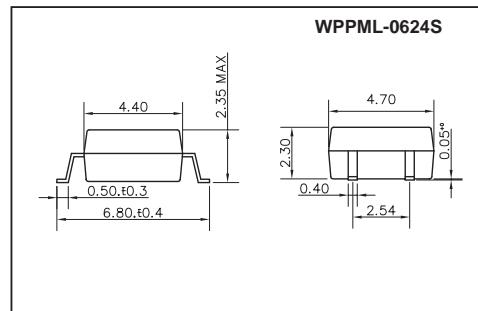
TLD: Tape Direction Left
TRU: Tape Direction Right

Not all combinations are available



Features

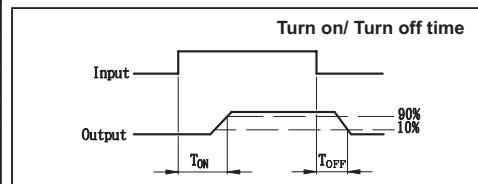
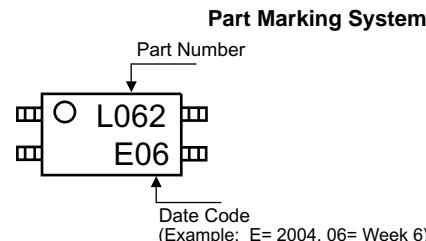
1. Normally open, single pole single throw.
2. Control 60VAC or DC voltage.
3. Switch 400mA loads.
4. LED control current, 2mA.
5. Low ON-resistance.
6. dv/dt, >500V/mS.
7. Isolation test voltage, 1500VRMS.



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Absolute Maximum Ratings

(Ta=25°C)	
Emitter (Input)	Detector (Output)
Reverse Voltage.....5.0V	Output Breakdown Voltage±60V
Continuous Forward Current50mA	Continuous Load Current±400mA
Peak Forward Current1A	Power Dissipation500mW
Power Dissipation100mW	
Derate Linearly from 25°C1.3mW/°C	
General Characteristics	
Isolation Test Voltage.....1500VRMS	Storage Temperature Range ...-40°C to +150°C
Isolation Resistance	Operating Temperature Range...-40°C to +85°C
VIO = 500V, TA = 25°C≥10 ¹⁰ Ω	Junction Temperature.....100°C
Total Power Dissipation550mW	Soldering Temperature,
Derate Linearly from 25°C2.5mW/°C	2mm from case, 10 sec260°C



Characteristics

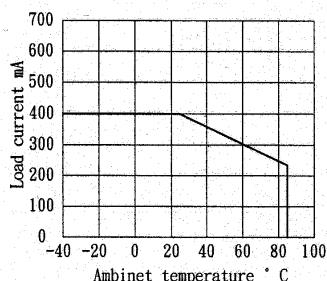
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Emitter (Input)						
Forward Voltage	VF	IF = 10mA		1.2	1.5	V
Operation Input Current	I _{FON}	V _L = ±20V, I _L = 100mA, t = 10ms			2	mA
Recovery Input Current	I _{FOFF}	V _L = ±20V, I _L ≤ 5μA	0.2			mA
Detector (Output)						
Output Breakdown Voltage	V _B	I _B = 50μA	60			V
Output Off-State Leakage	I _{TOFF}	V _T = 60V, I _F = 0mA	0.2	1		uA
I/O Capacitance	C _{ISO}	I _F = 0, f = 1MHz	6			pF
ON Resistance	R _{ON}	I _L = 100mA, I _F = 10mA	7	10		Ω
Turn-On Time	T _{ON}	I _F = 10mA, V _L = ±20V	0.2	1.5		ms
Turn-Off Time	T _{OFF}	t = 10mS, I _L = ±100mA	0.3	1.5		ms

MOS Relay Schematic and Wiring Diagrams

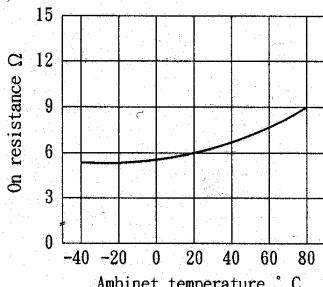
Type	Schematic	Output configuration	Load	Connection	Wiring Diagrams
0624S		1a	AC/DC	-	

Data Curve

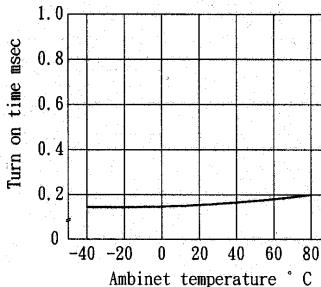
Load current vs. ambient temperature
Allowable ambient temperature:
-40°C to +85°C



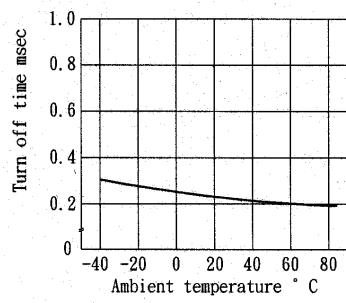
On resistance vs. ambient temperature
Across terminals 3 and 4 pin
LED current: 5mA
Continuous load current: 130 mA(DC)



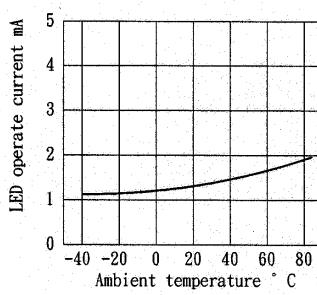
Turn on time vs. ambient temperature
Load voltage 60 V(DC)
LED current :5mA
Continuous load current: 130mA(DC)



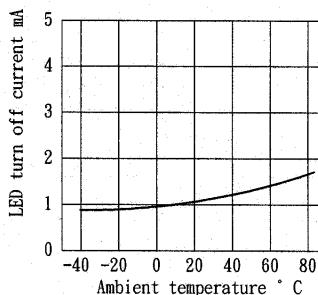
Turn off time vs. ambient temperature
LED current: 5mA;Load voltage: 60V(DC)
Continuous load current: 130mA(DC)



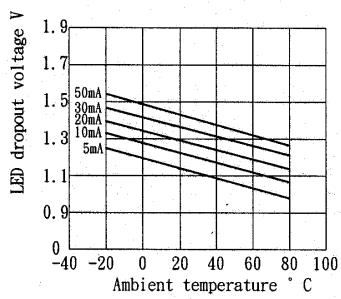
LED operate vs. ambient temperature
Load voltage: 60V(DC)
Continuous load current: 130mA(DC)



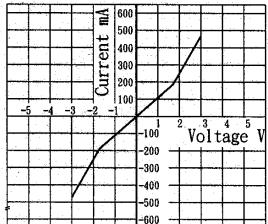
LED turn off current vs. ambient temperature
Load voltage: 60V(DC)
Continuons load current: 130mA(DC)



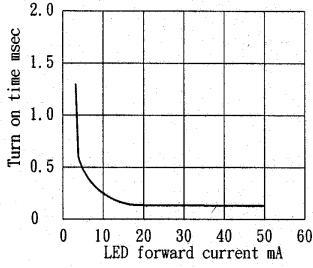
LED dropout voltage vs. ambient temperature
LED current: 5 to 50mA



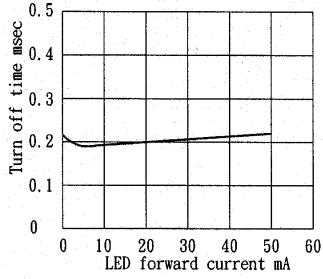
Voltage vs. current characteristics of output at MOS FET portion
Measured portion: across terminals 3 and 4 pin
Ambient temperature: 25° C



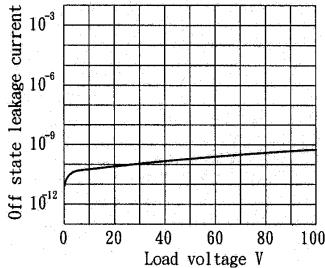
LED forward current vs. turn on time
Across terminals 3 and 4pin;Load voltage: 60V(DC);Continuous load current: 130mA(DC);Ambient temperature: 25° C



LED forward current vs. turn off time
Across terminals 3 and 4pin;Load voltage: 60V(DC);Continuous load current: 130 mA(DC);Ambient temperature: 25° C



Off state leakage current
Across terminals 3 and 4pin
Ambient temperature: 25° C



Applied voltage vs. output capacitance
Across terminals 3 and 4pin
Frequency: 1MHz;Ambient temperature: 25° C

